Product Preview

Power MOSFET 50 mAmps, 20 Volts

P-Channel SC-75

- Low Threshold Voltage: $V_{th} = 0.5$ to 1.5 V
- High Speed
- Small Package
- Complementary to NTES1N02

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

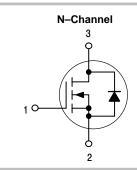
Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DS}	20	Vdc
Gate-to-Source Voltage - Continuous	VGSS	7	Vdc
Drain Current - Continuous @ T _A = 25°C	ΙD	50	mAdc
Total Power Dissipation @ T _A = 25°C	PD	100	mW
Channel Temperature	T _{ch}	150	°C
Operating and Storage Temperature Range	T _{stg}	- 55 to 150	°C



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50 mAMPS 20 VOLTS RDS(on) = 15 Ω



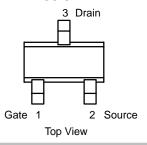
MARKING DIAGRAM





P02 = Device Code D = Date Code

PIN ASSIGNMENT



ORDERING INFORMATION

Device	Package	Shipping
NTES1P02	SC-75	3000 Tape & Reel

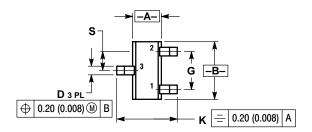
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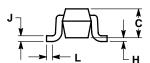
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Char	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 100 μA)		V(BR)DSS	20	_	-	Vdc
Drain Cut-off Current (V _{DS} = 20 Vdc, V _{GS} = 0 Vdc)		IDSS	_	_	1.0	μAdc
Gate–Body Leakage Current (V _{GS} = 7.0 Vdc, V _{DS} = 0)		IGSS	_	-	1.0	μAdc
ON CHARACTERISTICS						_
Gate Threshold Voltage (V _{DS} = 3.0 Vdc, I _D = 0.1 mAdc)		V _{th}	0.5	_	1.5	Vdc
Drain-to-Source On-Resistance (VGS = 2.5 Vdc, I _D = 10 mAdc)		R _{DS(on)}	-	7.0	15	Ω
Forward Transfer Admittance (V _{DS} = 3.0 Vdc, I _D = 10 mAdc)		YFS	15	-	-	mS
DYNAMIC CHARACTERISTICS						
Input Capacitance	$(V_{DS} = 3.0 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{iss}	_	10.4	-	pF
Output Capacitance	$(V_{DS} = 3.0 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{oss}	_	8.4	_	
Reverse Transfer Capacitance	$(V_{DS} = 3.0 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{rss}	_	2.8	-	
SWITCHING CHARACTERISTICS	•	· '		•		•
Turn-On Delay Time	(V _{DD} = 3.0 Vdc, I _D = 10 mAdc,	ton	_	0.15	-	μs
Turn-Off Delay Time	$V_{GS} = 0$ to 2.5 Vdc)	t _{off}	-	0.13	_	

PACKAGE DIMENSIONS

SC-75 (SC-90, SOT-416) CASE 463-01 ISSUE B





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.70	0.80	0.028	0.031	
В	1.40	1.80	0.055	0.071	
С	0.60	0.90	0.024	0.035	
D	0.15	0.30	0.006	0.012	
G	1.00 BSC		0.039 BSC		
Н		0.10		0.004	
J	0.10	0.25	0.004	0.010	
K	1.45	1.75	0.057	0.069	
L	0.10	0.20	0.004	0.008	
S	0.50 BSC		0.020 BSC		

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

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Toll Free from Hong Kong & Singapore:

001-800-4422-3781 Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center

4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031 **Phone**: 81–3–5740–2700

Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

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